



NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

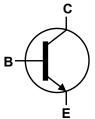
Mechanical Data

- Case: SOT323
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.006 grams (Approximate)

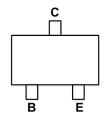








Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

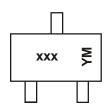
Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC846AW-7-F	AEC-Q101	K1Q	7	3,000
BC846BW-7-F	AEC-Q101	K1R	7	3,000
BC846BWQ-7-F	Automotive	K1R	7	3,000
BC846BW-13-F	AEC-Q101	K1R	13	10,000
BC847AW-7-F	AEC-Q101	K1Q	7	3,000
BC847BW-7-F	AEC-Q101	K1R	7	3,000
BC847BW-13-F	AEC-Q101	K1R	13	10,000

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC847BWQ-13-F	Automotive	K1R	13	10,000
BC847CW-7-F	AEC-Q101	K1M	7	3,000
BC847CW-13-F	AEC-Q101	K1M	13	10,000
BC847CWQ-7-F	Automotive	K1M	7	3,000
BC848AW-7-F	AEC-Q101	K1Q	7	3,000
BC848BW-7-F	AEC-Q101	K1R	7	3,000
BC848CW-7-F	AEC-Q101	K1M	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



xxx = Product Type Marking Code
(Please see Ordering Information)
YM = Date Code Marking
Y or Y = Year (ex: A = 2013)
M or M = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	X		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteri	stic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V_{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	V	6	V
Emitter-Base voltage	BC848	V _{EBO}	5	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic				Symbol	Min	Тур	Max	Unit	Test Condition	
		Е	3C846		80					
Collector-Base Breakdown Voltage		Е	BC847	BV _{CBO}	50	_	_	V	I _C = 100μA	
		Е	BC848		30					
		Е	3C846		65					
Collector-Emitter Breakdown V	/oltage (Note 8)	E	BC847	BV _{CEO}	45	_	_	V	I _C = 10mA	
		E	3C848		30					
Emitter-Base Breakdown Volta	ane	BC84	46, BC847	BV _{EBO}	6		_	V	I _E = 100μA	
Limiter-base Breakdown Volta		E	3C848	DAFRO	5			V	ΙΕ – 100μΑ	
			Α		110	180	220			
DC Current Gain (Note 8)	Current Gain Gr	oup	В	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$	
			С		420	520	800			
Collector Cutoff Current				I _{CBO}	_	_	20	nA	V _{CB} = 30V	
Collector Cutoff Current							5	μA	V _{CB} = 30V, T _A = +150°C	
Collector-Emitter Saturation Vo	oltago (Noto 9)			V _{CE(sat)}		90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
Collector-Emitter Saturation vo	ollage (Note 6)				_	200	600	1110	I _C = 100mA, I _B = 5.0mA	
Base-Emitter Turn-On Voltage	(Note 9)			.,	580	660	700	mV	I_C = 2mA, V_{CE} = 5V	
base-Emiller rum-On voltage	(Note 6)			V _{BE(on)}	_		770	IIIV	I _C = 10mA, V _{CE} = 5V	
Base-Emitter Saturation Voltage	ro (Noto 9)			\/·		700		mV	$I_C = 10$ mA, $I_B = 0.5$ mA	
Base-Emiller Saluration Voltag	ge (Note 6)			V _{BE(sat)}	_	900		IIIV	I _C = 100mA, I _B = 5mA	
Output Capacitance				C _{obo}	_	3	4.5	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequency			f _T	100	300	_	MHz	$V_{CE} = 5V, I_{C} = 10mA,$ f = 100MHz		
Noise Figure			NF	_	_	10	dB	V_{CE} = 5V, I_{C} = 200 μ A R_{S} = 2k Ω , f = 1kHz Δf = 200Hz		

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

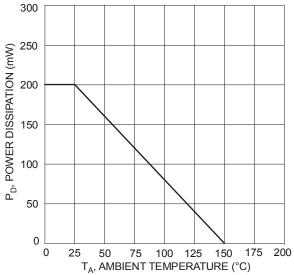


Figure 1 Power Dissipation vs. Ambient Temperature

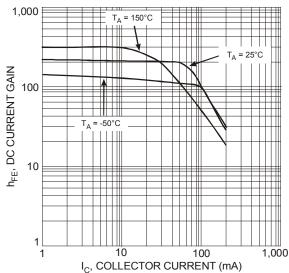


Figure 3 Typical DC Current Gain vs. Collector Current

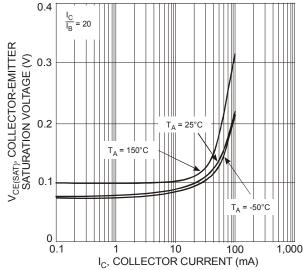


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

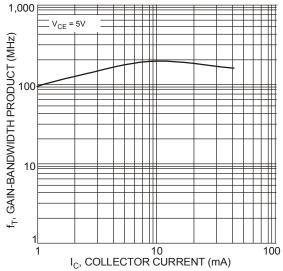
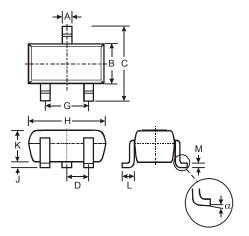


Figure 4 Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

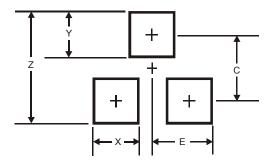
 $Please\ see\ AP02002\ at\ http://www.diodes.com/datasheets/ap02002.pdf\ for\ latest\ version.$



SOT323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
C	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
7	0.0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
M	0.10	0.18	0.11				
α	0°	8°	_				
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
E	1.0



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